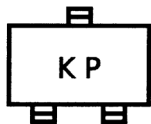


# 2SK2035

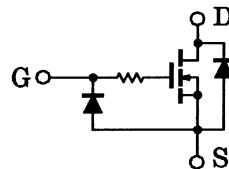
High Speed Switching Applications  
 Analog Switching Applications

- High input impedance.
- Low gate threshold voltage:  $V_{th} = 0.5 \sim 1.5 \text{ V}$
- Excellent switching times:  $t_{on} = 0.16 \mu\text{s}$  (typ.)  
 $t_{off} = 0.15 \mu\text{s}$  (typ.)
- Small package
- Enhancement-mode

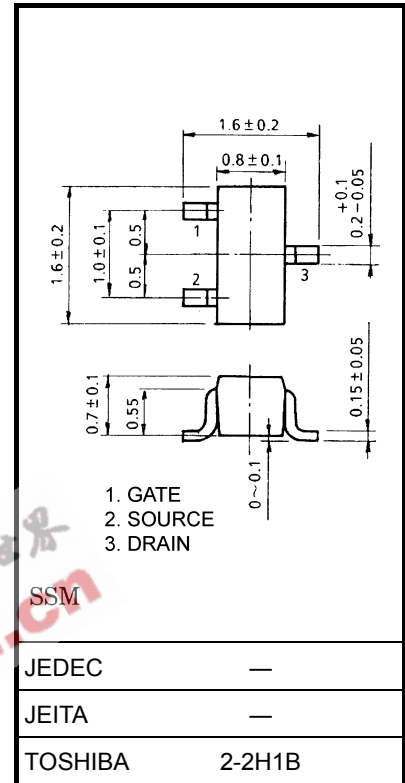
**Marking**



**Equivalent Circuit**



Unit: mm



Weight: 2.4 mg (typ.)

**Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DS}$	20	V
Gate-source voltage	$V_{GSS}$	10	V
Drain current	$I_D$	100	mA
Drain power dissipation	$P_D$	100	mW
Channel temperature	$T_{ch}$	150	°C
Storage temperature range	$T_{stg}$	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

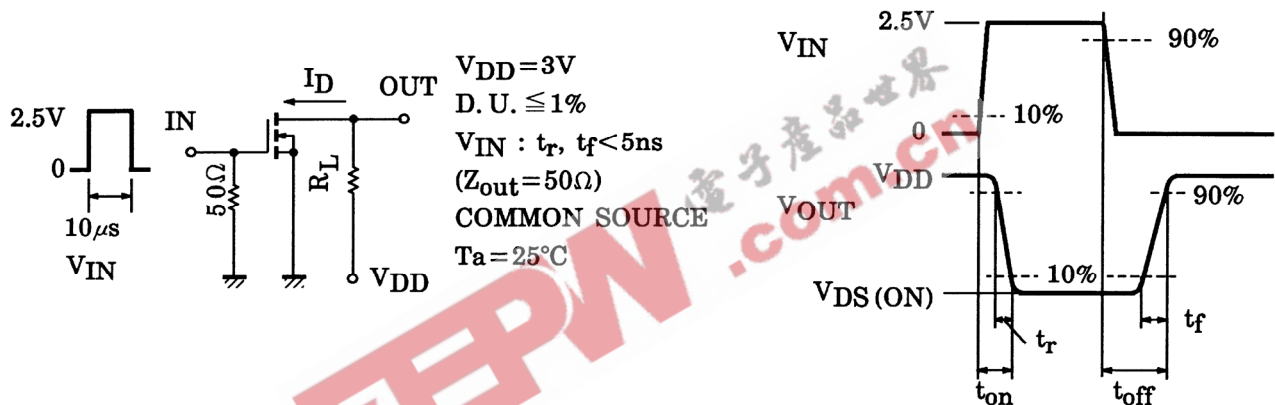
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

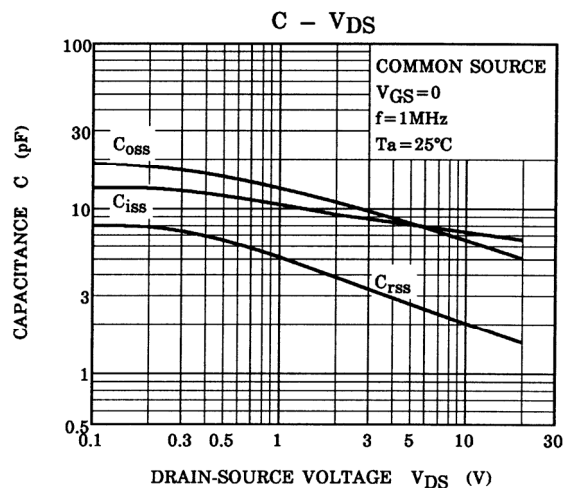
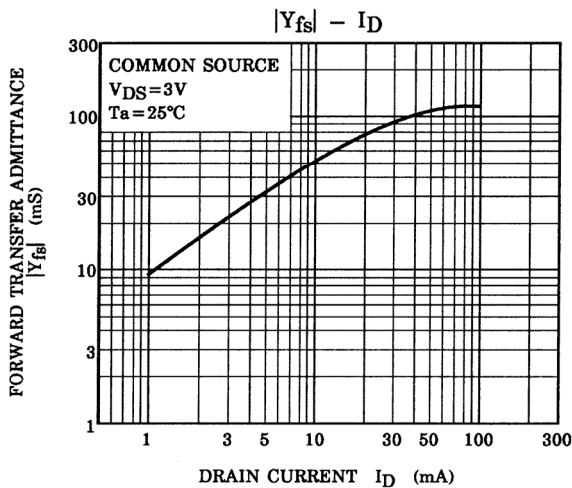
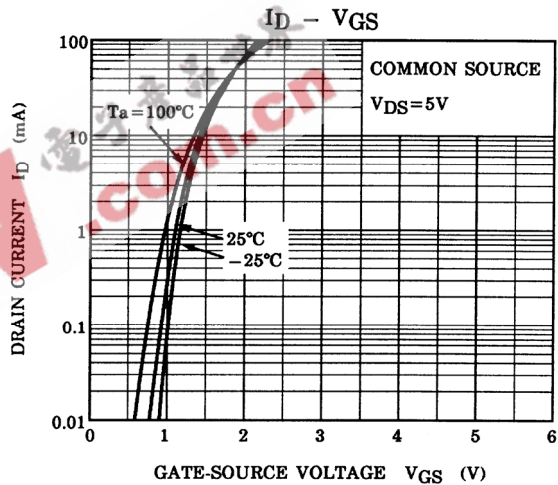
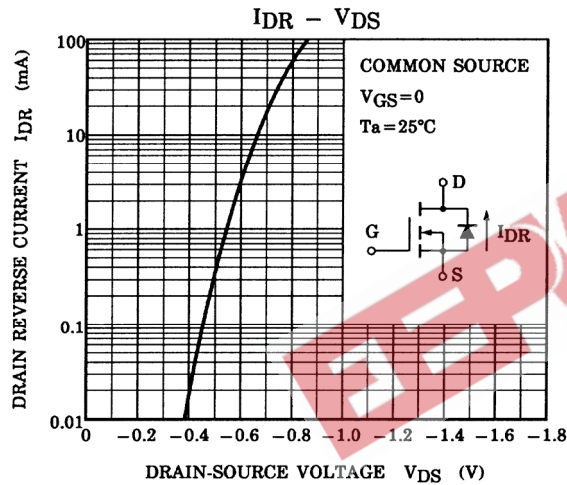
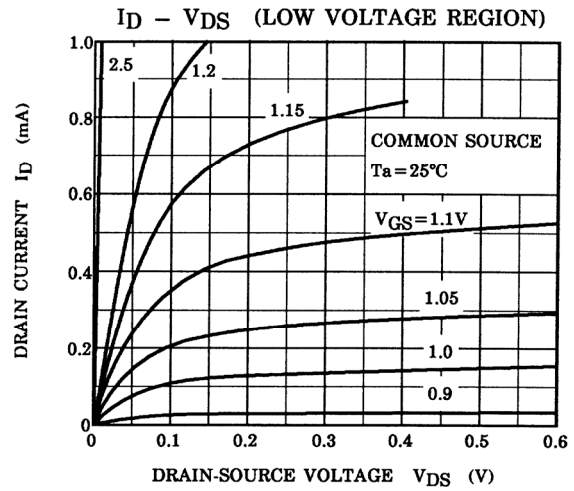
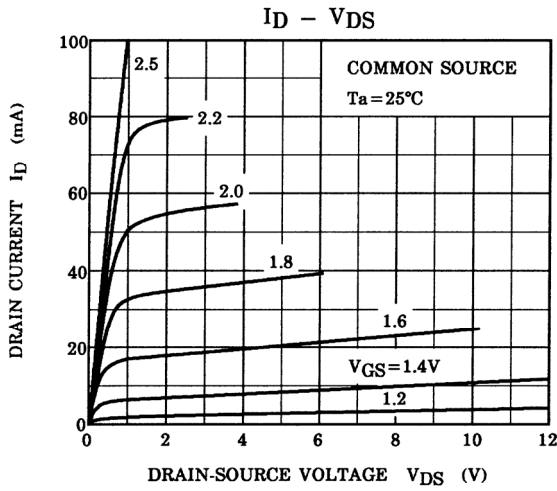
Note: This transistor is electrostatic sensitive device. Please handle with caution.

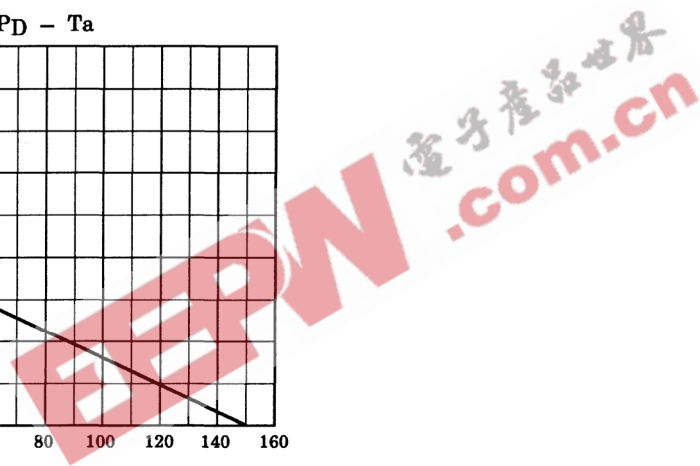
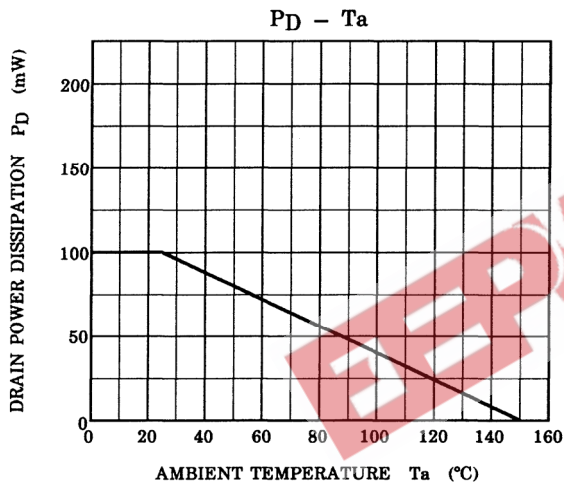
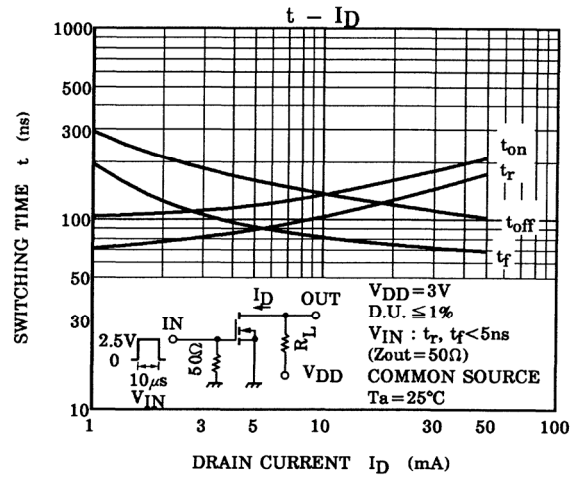
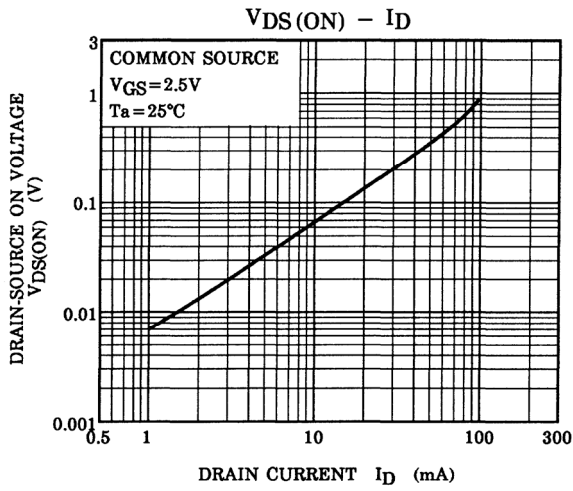
## Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Gate leakage current	$I_{GSS}$	$V_{GS} = 10\text{ V}, V_{DS} = 0$	—	—	1	$\mu\text{A}$	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 100\ \mu\text{A}, V_{GS} = 0$	20	—	—	V	
Drain cut-off current	$I_{DSS}$	$V_{DS} = 20\text{ V}, V_{GS} = 0$	—	—	1	$\mu\text{A}$	
Gate threshold voltage	$V_{th}$	$V_{DS} = 3\text{ V}, I_D = 0.1\text{ mA}$	0.5	—	1.5	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3\text{ V}, I_D = 10\text{ mA}$	25	50	—	mS	
Drain-source ON resistance	$R_{DS(ON)}$	$I_D = 10\text{ mA}, V_{GS} = 2.5\text{ V}$	—	8	12	$\Omega$	
Input capacitance	$C_{iss}$	$V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	8.5	—	pF	
Reverse transfer capacitance	$C_{rss}$	$V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	3.3	—	pF	
Output capacitance	$C_{oss}$	$V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	9.3	—	pF	
Switching time	Turn-on time	$t_{on}$	$V_{DD} = 3\text{ V}, I_D = 10\text{ mA}, V_{GS} = 0\sim 2.5\text{ V}$	—	0.16	—	$\mu\text{s}$
	Turn-off time	$t_{off}$	$V_{DD} = 3\text{ V}, I_D = 10\text{ mA}, V_{GS} = 0\sim 2.5\text{ V}$	—	0.15	—	

## Switching Time Test Circuit







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20070701-EN GENERAL

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